PATENT APPLICATION

DECLARATION AND POWER OF AT RNEY FOR PATENT APPLICATION						ATTORNEY DOCKET NO. <u>MA-094</u>		
are listed below) of the su Large Grain Size Polysili the specification of which () was filed on Number I hereby state that I have any amendment(s) referre CFR 1.56. Foreign Application(s) and/or	address and coll, first and solbject matter con Films Folia statched have a statched and to above.	itizenship are as state inventor (if only which is claimed and med by Nuclei-Indereto unless the foles and was amend I understood the collacknowledge the or go Priority	one name is list ad for which a paragraph of the paragrap	ed below) of tent is sought tent in the sought tent is sought tent in the sought tent is sought tent in the sought tent in the sought tent is sought tent in the sought tent in th	or an original, ght on the investation ternational Ap (if applicable ed specification which is n	ntion entitle plication). on, includin naterial to p	g the claims, as amended boatentability as defined in 3	
I hereby claim foreign priority have also identified below any f	benefits under Toreign application	itle 35, United States Con for patent or inventor	Code Section 119 of (s) certificate having	any foreign a a filing date	application(s) for before that of the	patent or inve application or	entor(s) certificate listed below an in which priority is claimed:	
COUNTRY A		ATION NUMBER	DATE FILED		PRIORITY CLAIMED UNDER 35 U.S.C. 119			
						YES:	NO:	
						YES:	NO:	
Provisional Application		· ·	<u>*</u>					
I hereby claim the benefit under	Title 35, United	States Code Section 11	9(e) of any United S	tates provisio	nal application(s)	listed below:		
	AP		APPLICATION SERIAL NUMBER FILI			NG DATE		
		AT EICATION SERVE NOME		TIENTO DATE				
							,	
acknowledge the duty to disclose material information application and the national or PCT international APPLICATION SERIAL NUMBER		nation as defined in Title 37, Code of Feder		r provided by the first paragraph of Title 35, United States Code Section 112, al Regulations, Section 1.56(a) which occurred between the filing date of the STATUS (patented/pending/abandoned)				
Trademark Office connected the			or agent(s) listed be			ion and trans	act all business in the Patent an	
Send Correspondence to: Pameta J. Squyres Matrix Semiconductor 3230 Scott Blyd Santa Clara, CA 95054					Direct Tele Pamela J. S 408-869-292	3.2.4	Co:	
	with the knowle	edge that willful false st	atements and the like	e so made are	punishable by fin	ie or imprison	are believed to be true; and further ment, or both, under Section 100 ued thereon.	
Full Name of Inventor: Shuo Gu					Citizenship: PR China			
Residence: 34077 Paseo Padr		Fremont, CA 94555			-r			
Post Office Address: Same								
Of Same				<u>~ / -</u>	1			
Thus t	tu			3/17/	103			
Inventor's Signature			Das	ie /				